Refine Search

Search Results -

Terms	Documents
L23 and (plasma same (ammonia or "NH.sub.3")) 12

US Pre-Grant Publication Full-Text Database

US Patents Full-Text Database

Database:

US OCR Full-Text Database EPO Abstracts Database JPO Abstracts Database

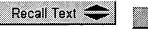
Derwent World Patents Index

IBM Technical Disclosure Bulletins

Search:

L26	
	*

Refine Search





Interrupt

Search History

DATE: Tuesday, March 30, 2004 Printable Copy Create Case

Set Name side by side	Query	Hit Count	Set Name result set
DB=P	PGPB, USPT, USOC, EPAB, JPAB, DWPI, TDBD; PLUR=YES; OP=ADJ		
<u>L26</u>	123 and (plasma same (ammonia or "NH.sub.3"))	12	<u>L26</u>
<u>L25</u>	L24 and plasma	22	<u>L25</u>
<u>L24</u>	L23 and (plasma or pecvd)	23	<u>L24</u>
<u>L23</u>	121 and (silicon nitride near2 interface)	23	<u>L23</u>
<u>L22</u>	L21 and (plasma same (ammonia or "NH.sub.3"))	34	<u>L22</u>
<u>L21</u>	118 and (oxide near8 nitride near8 interface)	98	<u>L21</u>
<u>L20</u>	119 and (oxide near8 nitride near8 interface)	9	<u>L20</u>
<u>L19</u>	L18 and (plasma same nitride near4 interface)	25	<u>L19</u>
<u>L18</u>	18 and thin film transistor	10870	<u>L18</u>
<u>L17</u>	L15 and (interface and nitride)	5	<u>L17</u>
<u>L16</u>	L15 and (interface near6 nitride)	2	<u>L16</u>
<u>L15</u>	"sung chae gee"	30	<u>L15</u>
<u>L14</u>	active polycrystalline silicon	20	<u>L14</u>

<u>L13</u>	L8 and ((silicon nitride near1 interface) same (plasma or pecvd))	24	<u>L13</u>
<u>L12</u>	L8 and (silicon nitride near1 interface)	209	<u>L12</u>
<u>L11</u>	L10 and (oxide same plasma same nitrous)	6	<u>L11</u>
<u>L10</u>	L9 and (nitride same plasma same ammonia same silane)	46	<u>L10</u>
<u>L9</u>	L8 and (silicon nitride near3 interface)	622	<u>L9</u>
<u>L8</u>	L7 or 16	350486	<u>L8</u>
<u>L7</u>	(257/\$).ccls.	281605	<u>L7</u>
<u>L6</u>	(438/\$).ccls.	153168	<u>L6</u>
DB=l	USPT; PLUR=YES; OP=ADJ		
<u>L5</u>	6045954.pn.	1	<u>L5</u>
DB=I	PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ		
<u>L4</u>	L3 and (nitrous same plasma)	5	<u>L4</u>
<u>L3</u>	(plasma same nitrid\$ same interface near6 silicon nitride) and ammonia and silane	33	<u>L3</u>
<u>L2</u>	(plasma same nitrid\$ same interface) and ammonia and silane	166	<u>L2</u>
<u>L1</u>	(active polycrystalline silicon or active polysilicon) same plasma same nitrid\$ same interface	2	<u>L1</u>

END OF SEARCH HISTORY